

SD1053C..L SERIES

FAST RECOVERY DIODES

Hockey Puk Version

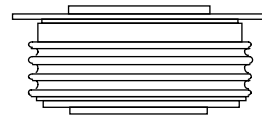
Features

- High power FAST recovery diode series
- 2.0 to 3.0 μ s recovery time
- High voltage ratings up to 3000V
- High current capability
- Optimized turn on and turn off characteristics
- Low forward recovery
- Fast and soft reverse recovery
- Press-puk encapsulation
- Case style conform to JEDEC DO-200AB (B-PUK)
- Maximum junction temperature 150°C

Typical Applications

- Snubber diode for GTO
- High voltage free-wheeling diode
- Fast recovery rectifier applications

920A
1050A



case style DO-200AB (B-PUK)

Major Ratings and Characteristics

Parameters	SD1053C..L		Units
	S20	S30	
$I_{F(AV)}$	1050	920	A
@ T_{hs}	55	55	°C
$I_{F(RMS)}$	1940	1700	A
I_{FSM} @ 50Hz	15000	13000	A
@ 60Hz	15700	13610	A
V_{RRM} range	1800 to 2500	1800 to 3000	V
t_{rr}	2.0	3.0	μ s
@ T_J	25	25	°C
T_J	- 40 to 150		°C

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International
IR Rectifier**ELECTRICAL SPECIFICATIONS****Voltage Ratings**

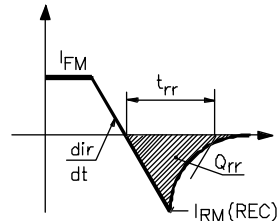
Type number	Voltage Code	V_{RRM} , maximum repetitive peak reverse voltage V	V_{RSM} , maximum non-repetitive peak rev. voltage V	I_{RRM} max. @ $T_J = T_J$ max. mA
SD1053C..S20L	18	1800	1900	50
	22	2200	2300	
	25	2500	2600	
SD1053C..S30L	18	1800	1900	
	22	2200	2300	
	25	2500	2600	
	28	2800	2900	
	30	3000	3100	

Forward Conduction

Parameter		SD1053C..L		Units	Conditions			
		S20	S30					
I _{F(AV)}	Max. average forward current @ heatsink temperature	1050(450)	920(390)	A	180° conduction, half sine wave			
		55 (85)	55 (85)	°C	Double side (single side) cooled			
I _{F(RMS)}	Max. RMS forward current	1940	1700	A	@ 25°C heatsink temperature double side cooled			
I _{FSM}	Max. peak, one-cycle forward, non-repetitive surge current	15000	13000	A	t = 10ms	No voltage	Sinusoidal half wave, Initial T _J = T _J max.	
		15700	13610		t = 8.3ms	reapplied		
		12620	10930		t = 10ms	100% V _{RRM}		
		13210	11450		t = 8.3ms	reapplied		
I ² t	Maximum I ² t for fusing	1125	845	KA ² s	t = 10ms	No voltage		
		1027	772		t = 8.3ms	reapplied		
		796	598		t = 10ms	100% V _{RRM}		
		727	546		t = 8.3ms	reapplied		
I ² √t	Maximum I ² √t for fusing	11250	8450	KA ² √s	t = 0.1 to 10ms, no voltage reapplied			
V _{F(TO)1}	Low level value of threshold voltage	1.34	1.51	V	(16.7% × π × I _{F(AV)}) < I < π × I _{F(AV)} , T _J = T _J max.			
V _{F(TO)2}	High level value of threshold voltage	1.48	1.67		(I > π × I _{F(AV)}), T _J = T _J max.			
r _{f1}	Low level value of forward slope resistance	0.37	0.50	mΩ	(16.7% × π × I _{F(AV)}) < I < π × I _{F(AV)} , T _J = T _J max.			
r _{f2}	High level value of forward slope resistance	0.33	0.45		(I > π × I _{F(AV)}), T _J = T _J max.			
V _{FM}	Max. forward voltage drop	1.90	2.26	V	I _{pk} = 1500A, T _J = T _J max, t _p = 10ms sinusoidal wave			

Recovery Characteristics

Code	$T_J = 25^\circ\text{C}$ Typical t_{rr} @ 25% I_{RRM} (μs)	Test conditions			Max. values @ $T_J = 150^\circ\text{C}$		
		I_{pk} Square Pulse (A)	di/dt (A/ μs)	V_r (V)	t_{rr} @ 25% I_{RRM} (μs)	Q_{rr} (μC)	I_{rr} (A)
S20	2.0	1000	100	- 50	4.0	400	180
S30	3.0	1000	100	- 50	4.5	550	230



Thermal and Mechanical Specifications

Parameter		SD1053C..L		Units	Conditions
		S20	S30		
T _J	Max. junction operating temperature range	-40 to 150		°C	
T _{stg}	Max. storage temperature range	-40 to 150			
R _{thJ-hs}	Max. thermal resistance, case junction to heatsink	0.073 0.031		K/W	DCoperation single side cooled DCoperation double side cooled
F	Mounting force, ± 10%	14700 (1500)		N (Kg)	
wt	Approximate weight	255		g	
Case style		DO-200AB(B-PUK)			See Outline Table

ΔR_{thJ-hs} Conduction

(The following table shows the increment of thermal resistance R_{thJ-hs} when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction		Rectangular conduction		Units	Conditions
	Single Side	Double Side	Single Side	Double Side		
180°	0.009	0.008	0.006	0.006	K/W	$T_J = T_{J \text{ max.}}$
120°	0.011	0.011	0.011	0.011		
90°	0.014	0.014	0.015	0.015		
60°	0.020	0.021	0.021	0.022		
30°	0.036	0.036	0.036	0.036		

Ordering Information Table

Device Code						
SD	105	3	C	30	S30	L
(1)	(2)	(3)	(4)	(5)	(6)	(7)
1	- Diode					
2	- Essential part number					
3	- 3 = Fast recovery					
4	- C = Ceramic Puk					
5	- Voltage code: Code x 100 = V_{RRM} (See Voltage Ratings table)					
6	- t_{rr} code					
7	- L = Puk Case DO-200AB(B-PUK)					

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Outline Table

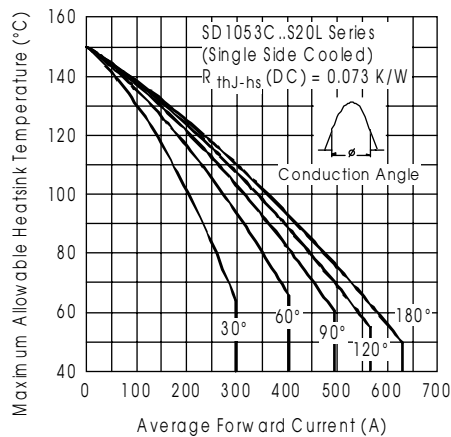
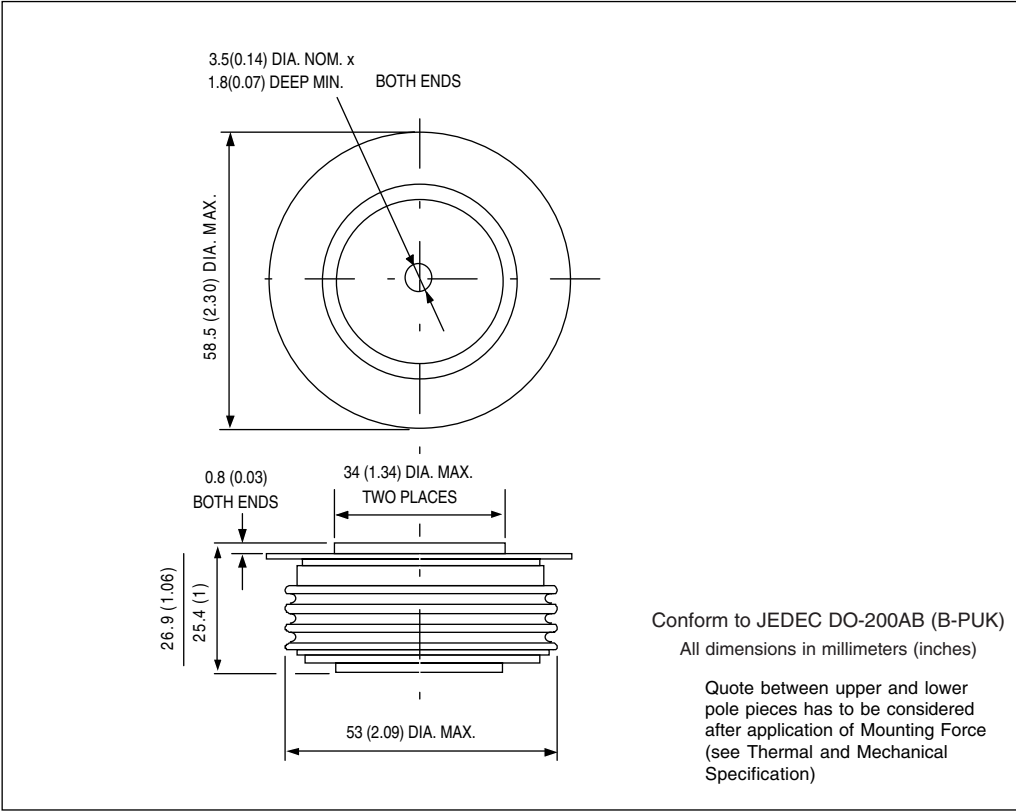


Fig. 1 - Current Ratings Characteristics

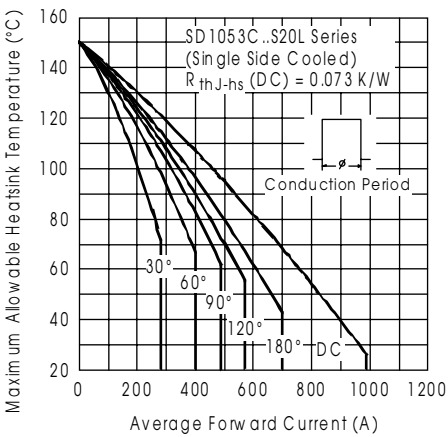


Fig. 2 - Current Ratings Characteristics

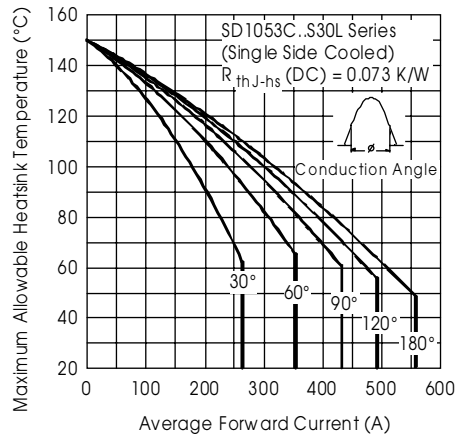


Fig. 3 - Current Ratings Characteristics

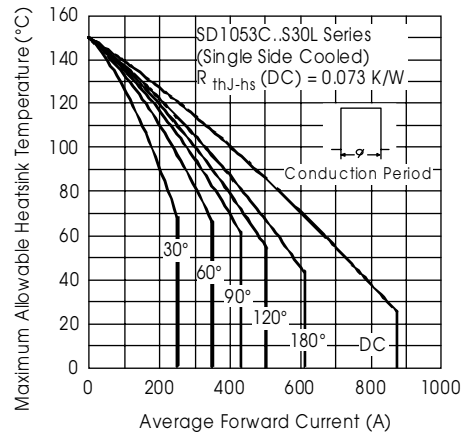


Fig. 4 - Current Ratings Characteristics

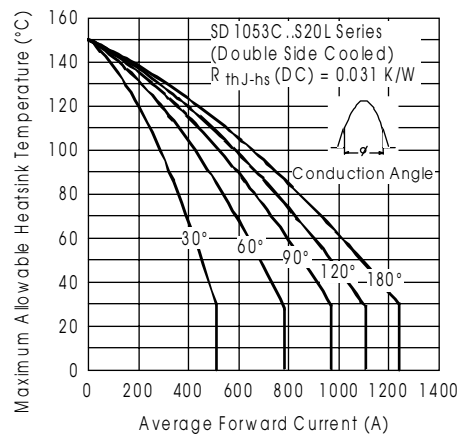


Fig. 5 - Current Ratings Characteristics

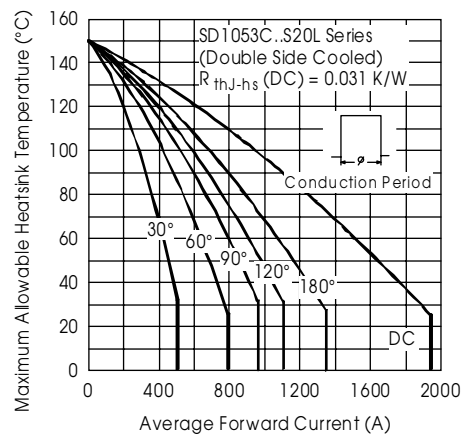


Fig. 6 - Current Ratings Characteristics

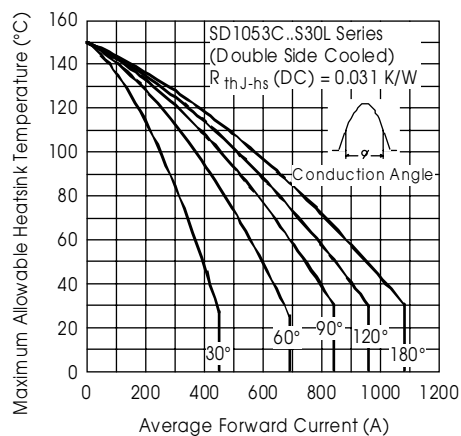


Fig. 7 - Current Ratings Characteristics

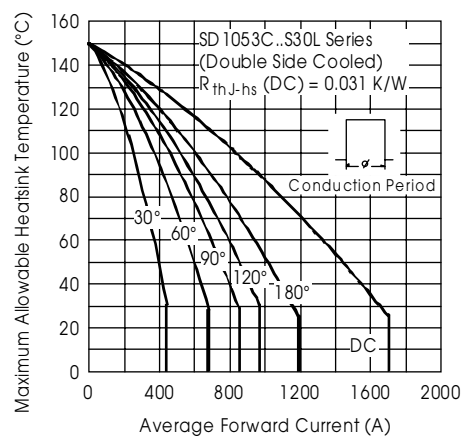


Fig. 8 - Current Ratings Characteristics

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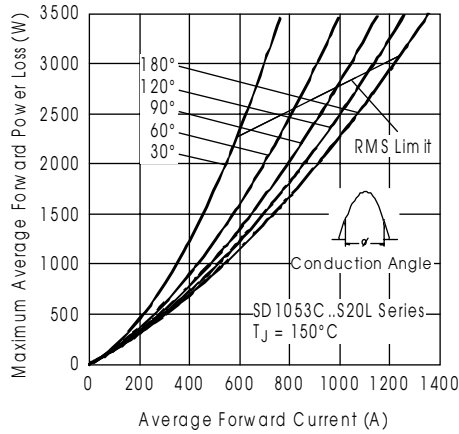


Fig. 9 - Forward Power Loss Characteristics

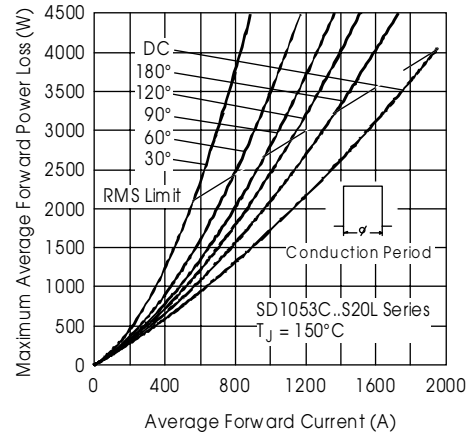


Fig. 10 - Forward Power Loss Characteristics

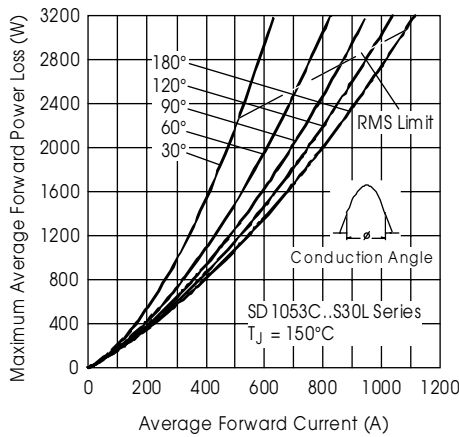


Fig. 11 - Forward Power Loss Characteristics

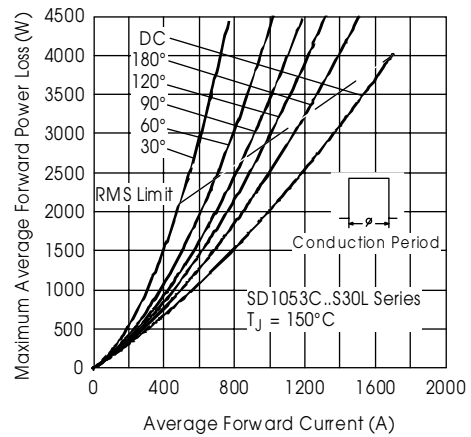


Fig. 12 - Forward Power Loss Characteristics

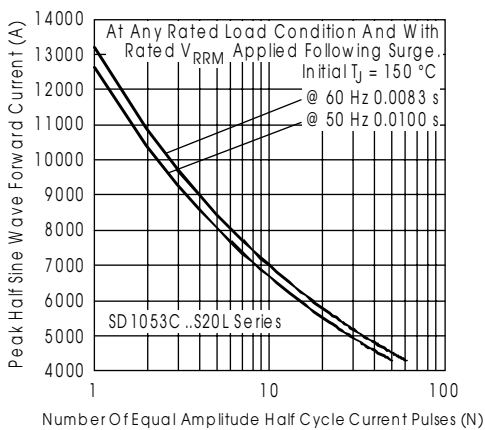


Fig. 13 - Maximum Non-repetitive Surge Current
Single and Double Side Cooled

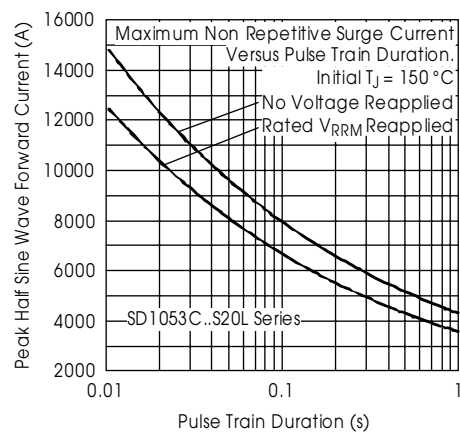


Fig. 14 - Maximum Non-repetitive Surge Current
Single and Double Side Cooled

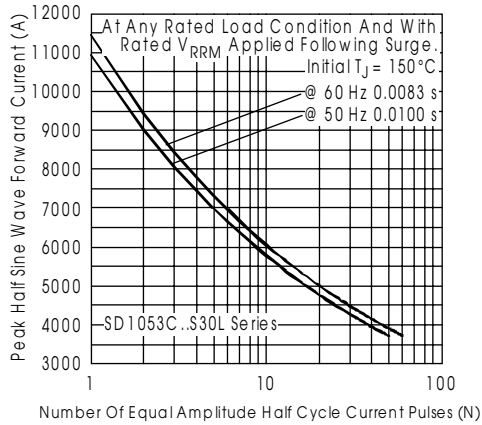


Fig. 15 - Maximum Non-repetitive Surge Current Single and Double Side Cooled

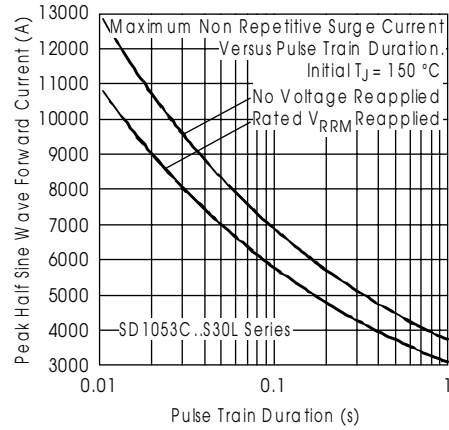


Fig. 16 - Maximum Non-repetitive Surge Current Single and Double Side Cooled

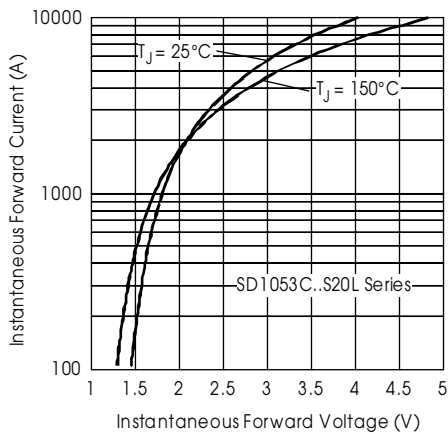


Fig. 17 - Forward Voltage Drop Characteristics

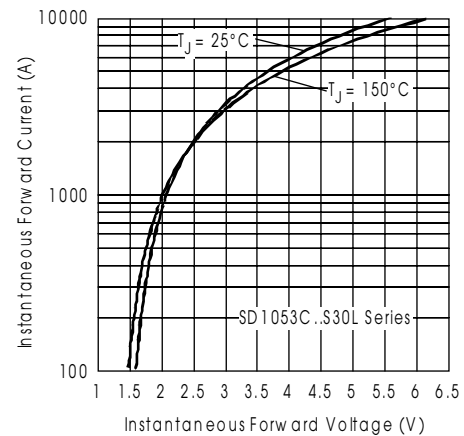


Fig. 18 - Forward Voltage Drop Characteristics

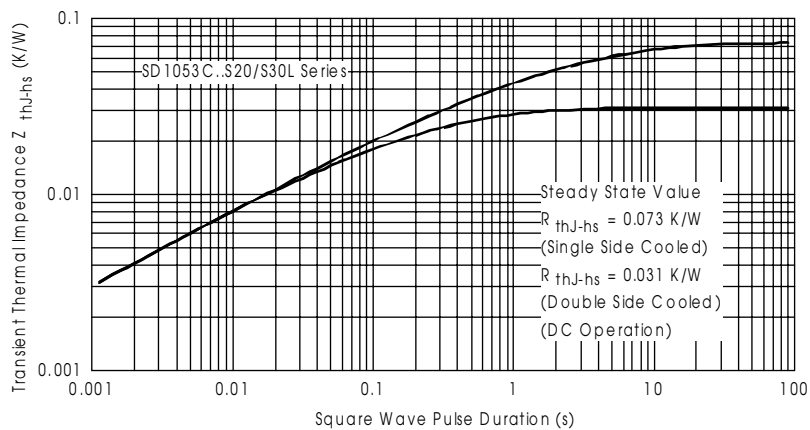


Fig. 19 - Thermal Impedance Z_{thJ-hs} Characteristic

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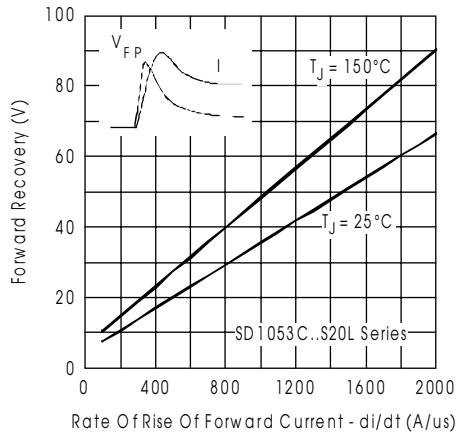


Fig. 20 - Typical Forward Recovery Characteristics

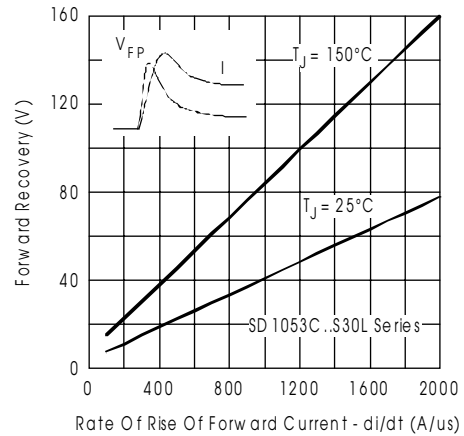


Fig. 21 - Typical Forward Recovery Characteristics

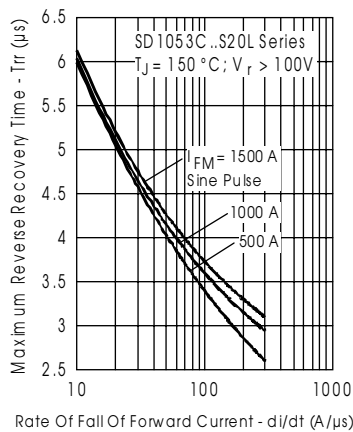


Fig. 22 - Recovery Time Characteristics

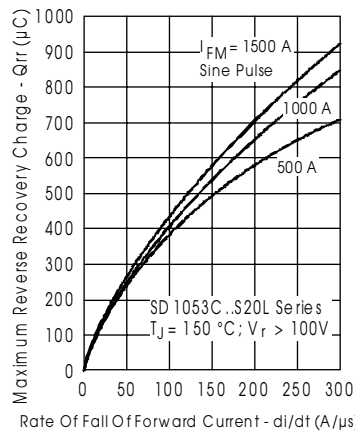


Fig. 23 - Recovery Charge Characteristics

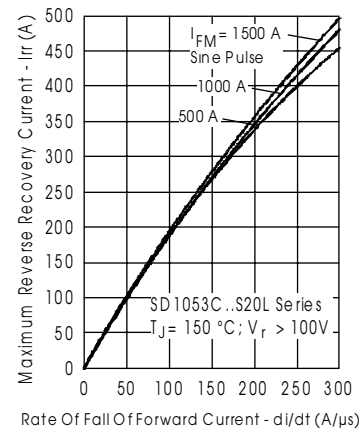


Fig. 24 - Recovery Current Characteristics

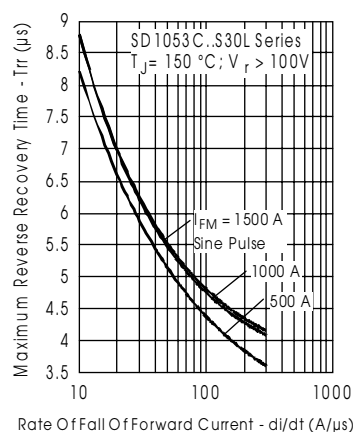


Fig. 25 - Recovery Time Characteristics

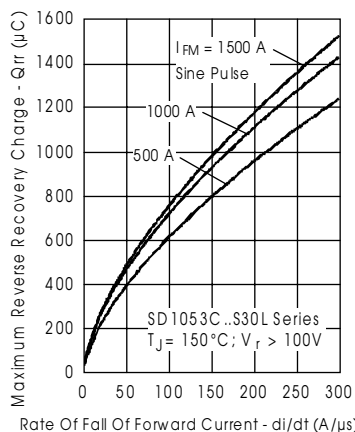


Fig. 26 - Recovery Charge Characteristics

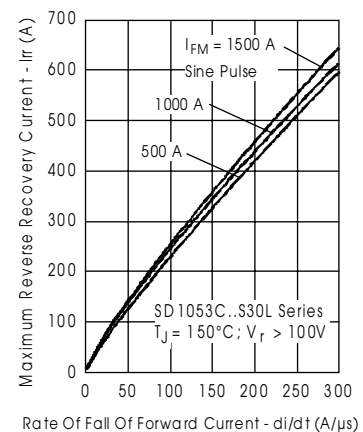


Fig. 27 - Recovery Current Characteristics

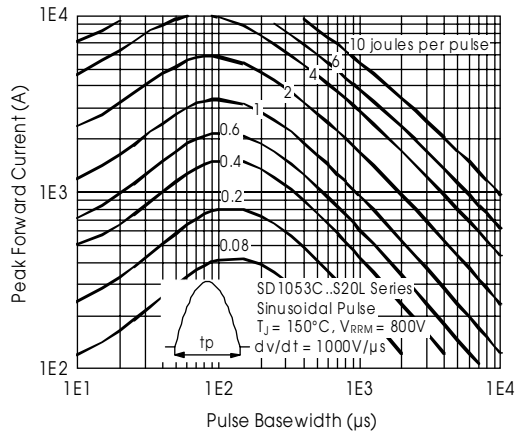


Fig. 28 - Maximum Total Energy Loss Per Pulse Characteristics

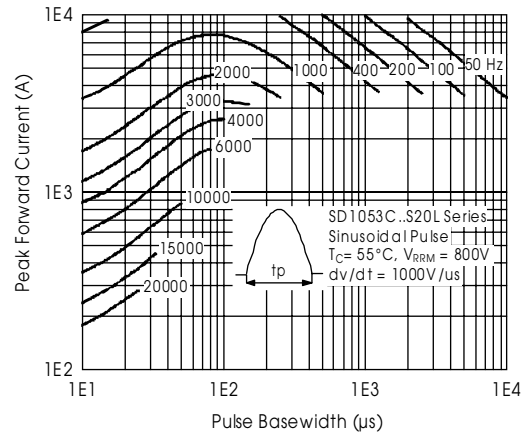


Fig. 29 - Frequency Characteristics

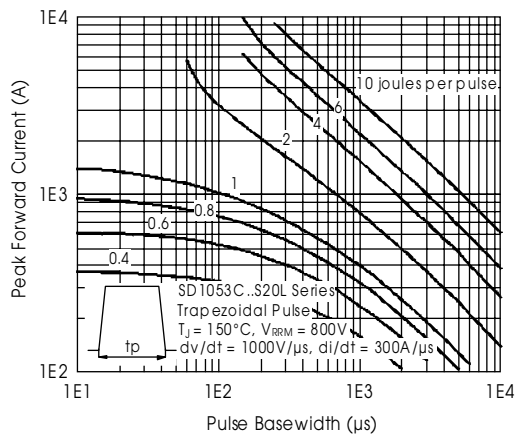


Fig. 30 - Maximum Total Energy Loss Per Pulse Characteristics

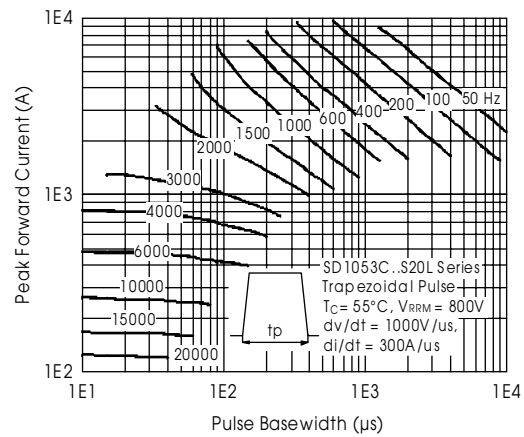


Fig. 31 - Frequency Characteristics

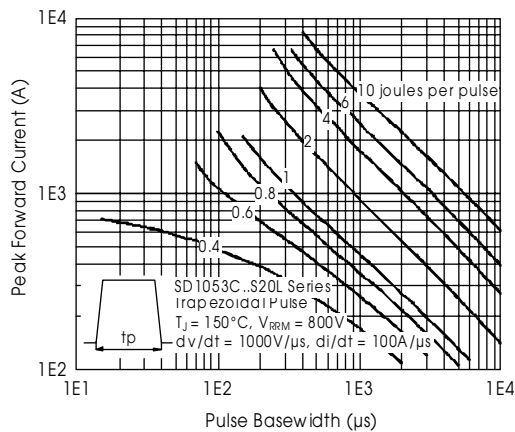


Fig. 32 - Maximum Total Energy Loss Per Pulse Characteristics

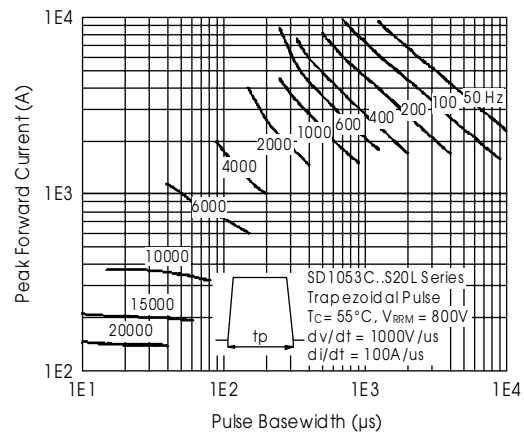


Fig. 33 - Frequency Characteristics

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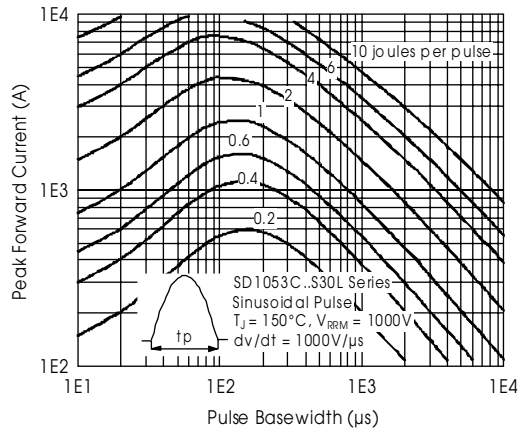


Fig. 34 - Maximum Total Energy Loss Per Pulse Characteristics

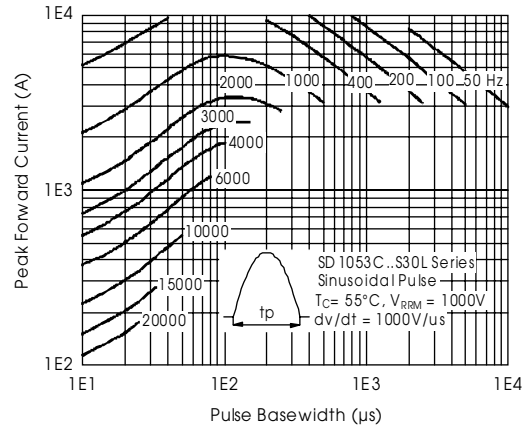


Fig. 35 - Frequency Characteristics

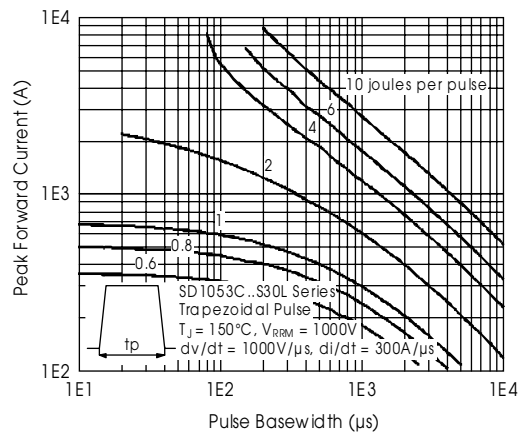


Fig. 36 - Maximum Total Energy Loss Per Pulse Characteristics

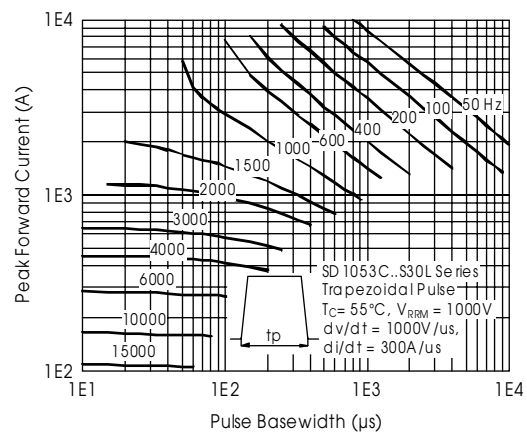


Fig. 37 - Frequency Characteristics

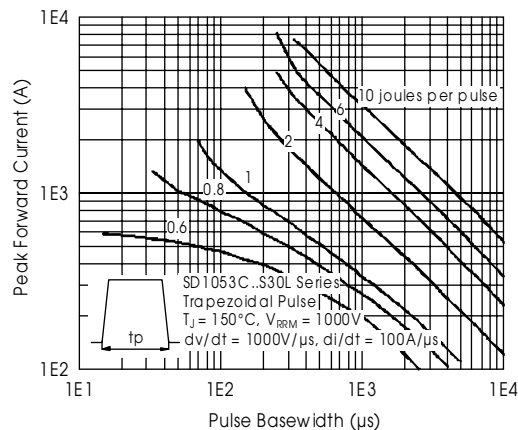


Fig. 38 - Maximum Total Energy Loss Per Pulse Characteristics

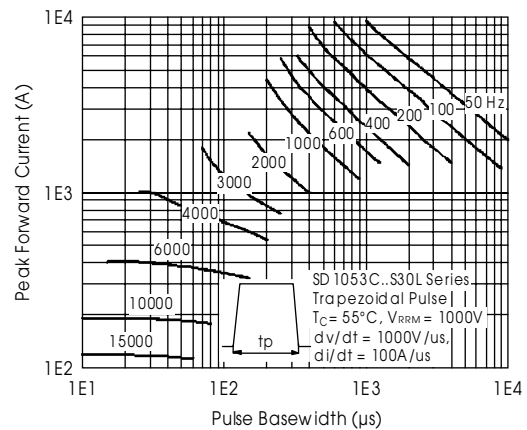


Fig. 39 - Frequency Characteristics